

The RF Line

NPN Silicon

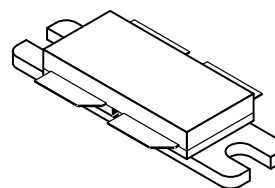
RF Power Transistor

Designed for 26 Volt UHF large-signal, common emitter, Class AB linear amplifier applications in industrial and commercial FM/AM equipment operating in the range 800–960 MHz.

- Specified 26 Volt, 900 MHz Characteristics
 - Output Power = 150 Watts (PEP)
 - Minimum Gain = 8.0 dB @ 900 MHz, Class AB
 - Minimum Efficiency = 35% @ 900 MHz, 150 Watts (PEP)
 - Maximum Intermodulation Distortion –28 dBc @ 150 Watts (PEP)
- Characterized with Series Equivalent Large-Signal Parameters from 800 to 960 MHz
- Silicon Nitride Passivated
- 100% Tested for Load Mismatch Stress at all Phase Angles with 5:1 VSWR @ 26 Vdc, and Rated Output Power
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

MRF899

**150 W, 900 MHz
RF POWER
TRANSISTOR
NPN SILICON**



CASE 375A-01, STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	28	Vdc
Collector–Emitter Voltage	V_{CES}	60	Vdc
Emitter–Base Voltage	V_{EBO}	4.0	Vdc
Collector–Current — Continuous	I_C	25	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	230 1.33	Watts W/ $^\circ\text{C}$
Storage Temperature Range	T_{stg}	–65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.75	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 100\text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	28	37	—	Vdc
Collector–Emitter Breakdown Voltage ($I_C = 50\text{ mAdc}$, $V_{BE} = 0$)	$V_{(BR)CES}$	60	85	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10\text{ mAdc}$, $I_C = 0$)	$V_{(BR)EBO}$	4.0	4.9	—	Vdc
Collector Cutoff Current ($V_{CE} = 30\text{ Vdc}$, $V_{BE} = 0$)	I_{CES}	—	—	10	mAdc

ON CHARACTERISTICS

DC Current Gain ($I_{CE} = 1.0\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$)	h_{FE}	30	75	120	—
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DYNAMIC CHARACTERISTICS

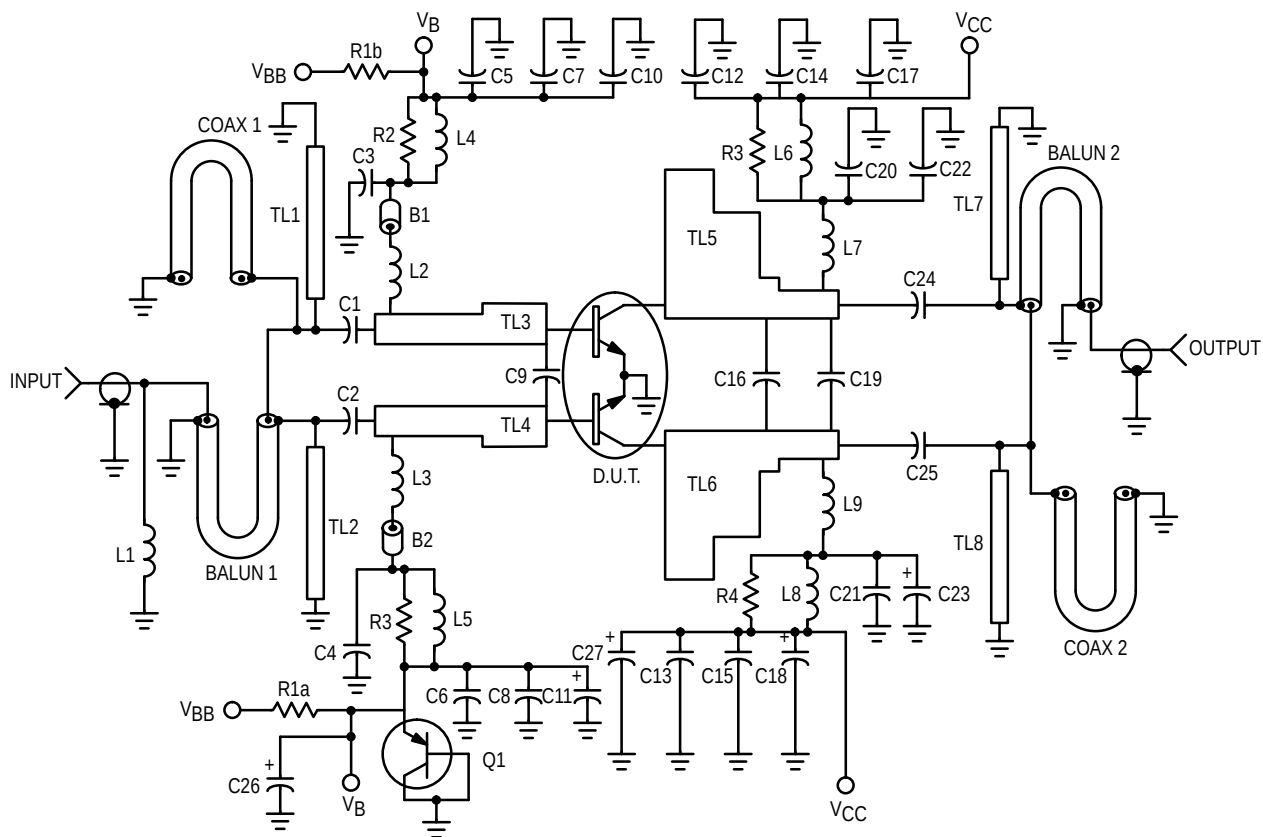
Output Capacitance ($V_{CB} = 26\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$) (1)	C_{ob}	—	75	—	pF
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(1) For information only. This part is collector matched.

(continued)

ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
FUNCTIONAL CHARACTERISTICS					
Common–Emitter Amplifier Power Gain V _{CC} = 26 Vdc, P _{out} = 150 Watts (PEP), I _{cq} = 300 mA, f ₁ = 900 MHz, f ₂ = 900.1 MHz	G _{pe}	8.0	9.0	—	dB
Collector Efficiency V _{CC} = 26 Vdc, P _{out} = 150 Watts (PEP), I _{cq} = 300 mA, f ₁ = 900 MHz, f ₂ = 900.1 MHz	η	30	40	—	%
3rd Order Intermodulation Distortion V _{CC} = 26 Vdc, P _{out} = 150 Watts (PEP), I _{cq} = 300 mA, f ₁ = 900 MHz, f ₂ = 900.1 MHz	IMD	—	–32	–28	dBc
Output Mismatch Stress V _{CC} = 26 Vdc, P _{out} = 150 Watts (PEP), I _{cq} = 300 mA, f ₁ = 900 MHz, f ₂ = 900.1 MHz, VSWR = 5:1 (all phase angles)	ψ	No Degradation in Output Power Before and After Test			



B1, B2 — Ferrite Bead, Ferroxcube #56–590–65–3B
C1, C2, C24, C25 — 43 pF, B Case, ATC Chip Capacitor
C3, C4, C20, C21 — 100 pF, B Case, ATC Chip Capacitor
C5, C6, C12, C13 — 1000 pF, B Case, ATC Chip Capacitor
C7, C8, C14, C15 — 1800 pF, AVX Chip Capacitor
C9 — 9.1 pF, A Case, ATC Chip Capacitor
C10, C11, C17, C18, C22, C23 — 10 μ F, Electrolytic Capacitor
Panasonic
C16 — 3.9 pF, B Case, ATC Chip Capacitor
C19 — 0.8 pF, B Case, ATC Chip Capacitor
C26 — 200 μ F, Electrolytic Capacitor Mallory Sprague
C27 — 500 μ F Electrolytic Capacitor

L1 — 5 Turns 24 AWG IDIA 0.059" Choke, 19.8 nH
L2, L3, L7, L9 — 4 Turns 20 AWG IDIA 0.163" Choke
L4, L5, L6, L8 — 12 Turns 22 AWG IDIA 0.140" Choke
N1, N2 — Type N Flange Mount, Omni Spectra
Q1 — Bias Transistor BD136 PNP
R2, R3, R4, R5 — 4.0 x 39 Ohm 1/8 W Chips in Parallel
R1a, R1b — 56 Ohm 1.0 W
TL1–TL8 — See Photomaster
Balun1, Balun2, Coax 1, Coax 2 — 2.20" 50 Ohm 0.088" o.d.
Semi-rigid Coax, Micro Coax
Board — 1/32" Glass Teflon, $\epsilon_r = 2.55$ " Arlon (GX-0300-55-22)

Figure 1. 900 MHz Power Gain Test Circuit

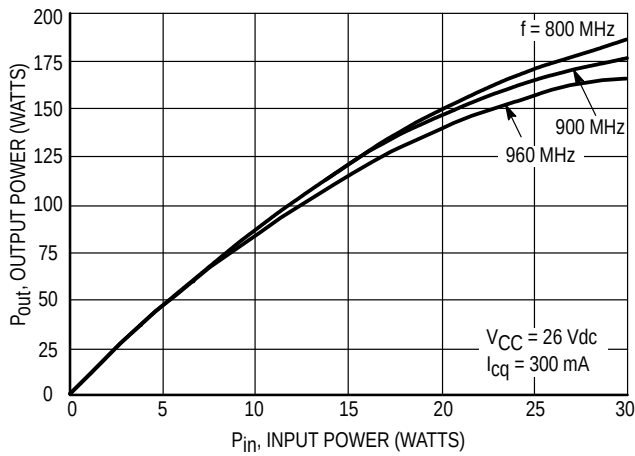


Figure 2. Output Power versus Input Power

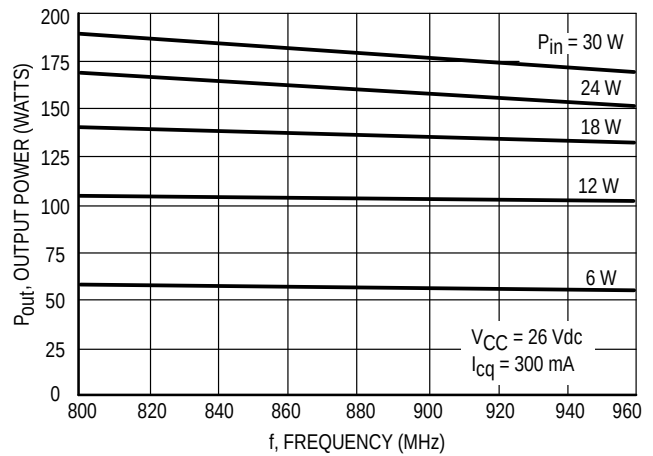


Figure 3. Output Power versus Frequency

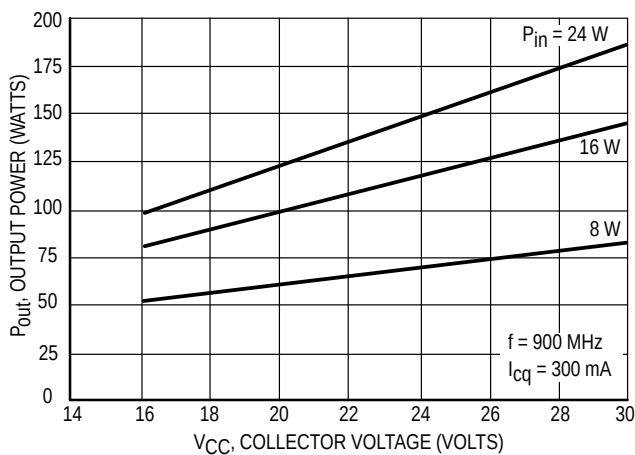


Figure 4. Output Power versus Supply Voltage

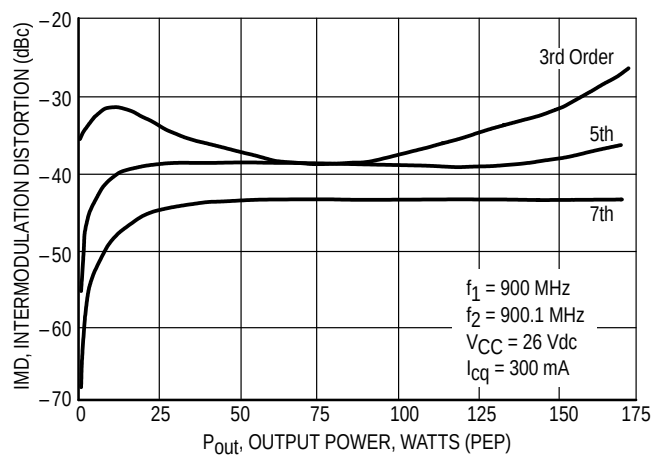


Figure 5. Intermodulation versus Output Power

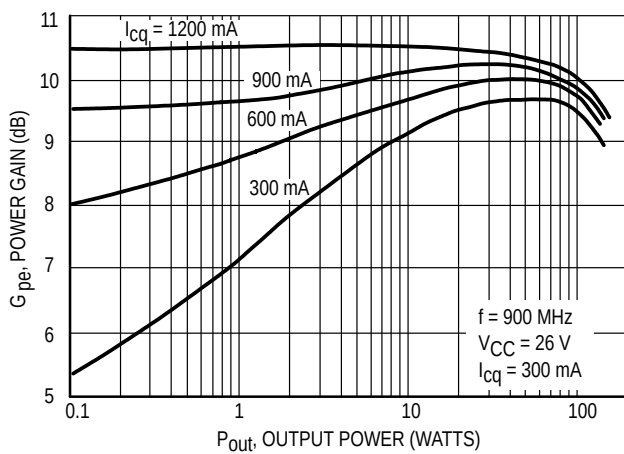


Figure 6. Power Gain versus Output Power

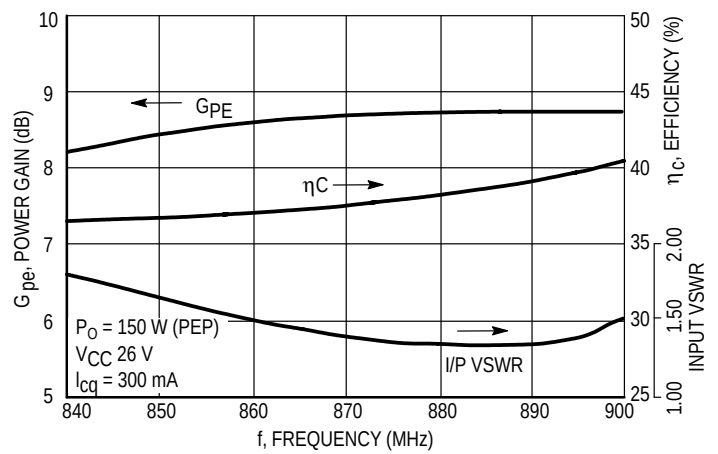
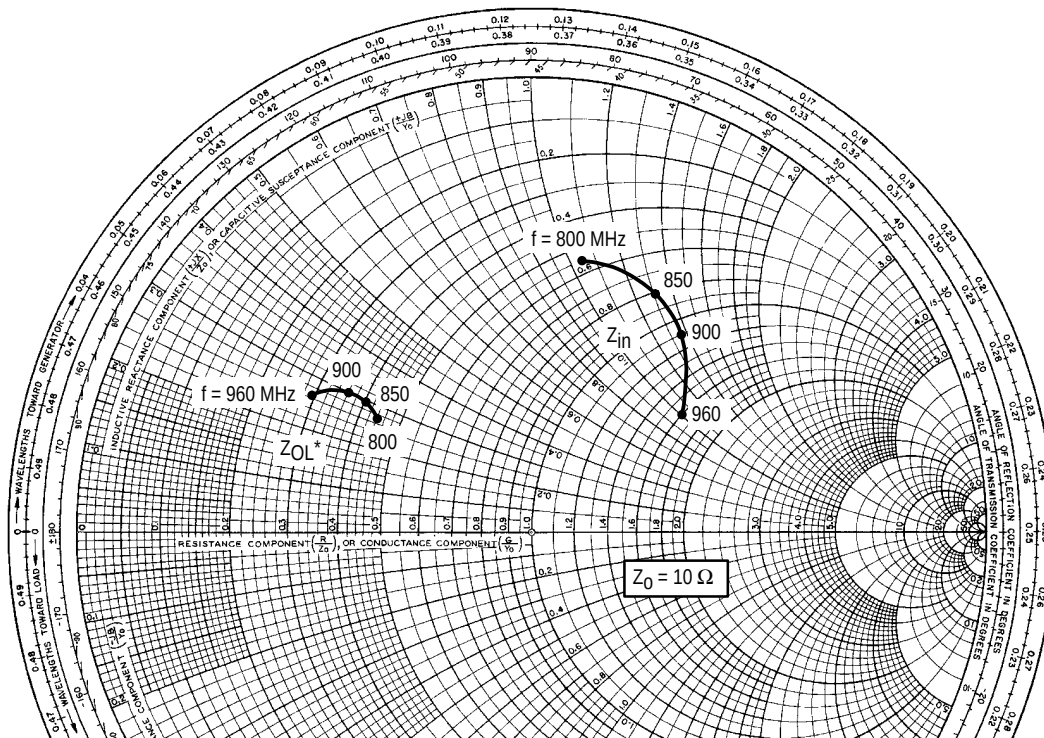


Figure 7. Broadband Test Fixture Performance



f MHz	Z_{in} Ohms	Z_{OL}^* Ohms
800	$5.51 + j10.6$	$4.52 + j2.64$
850	$8.17 + j13.2$	$4.21 + j2.98$
900	$11.2 + j13.8$	$3.68 + j2.97$
960	$16.8 + j10.1$	$2.98 + j2.71$

NOTE: Z_{in} & Z_{OL}^* are given from base-to-base and collector-to-collector respectively

Z_{OL}^* = Conjugate of optimum load impedance into which the device operates at a given output power, voltage and frequency.

Figure 8. Input and Output Impedances
with Circuit Tuned for Maximum Gain @ $P_O = 150$ W (PEP), $V_{CC} = 26$ V

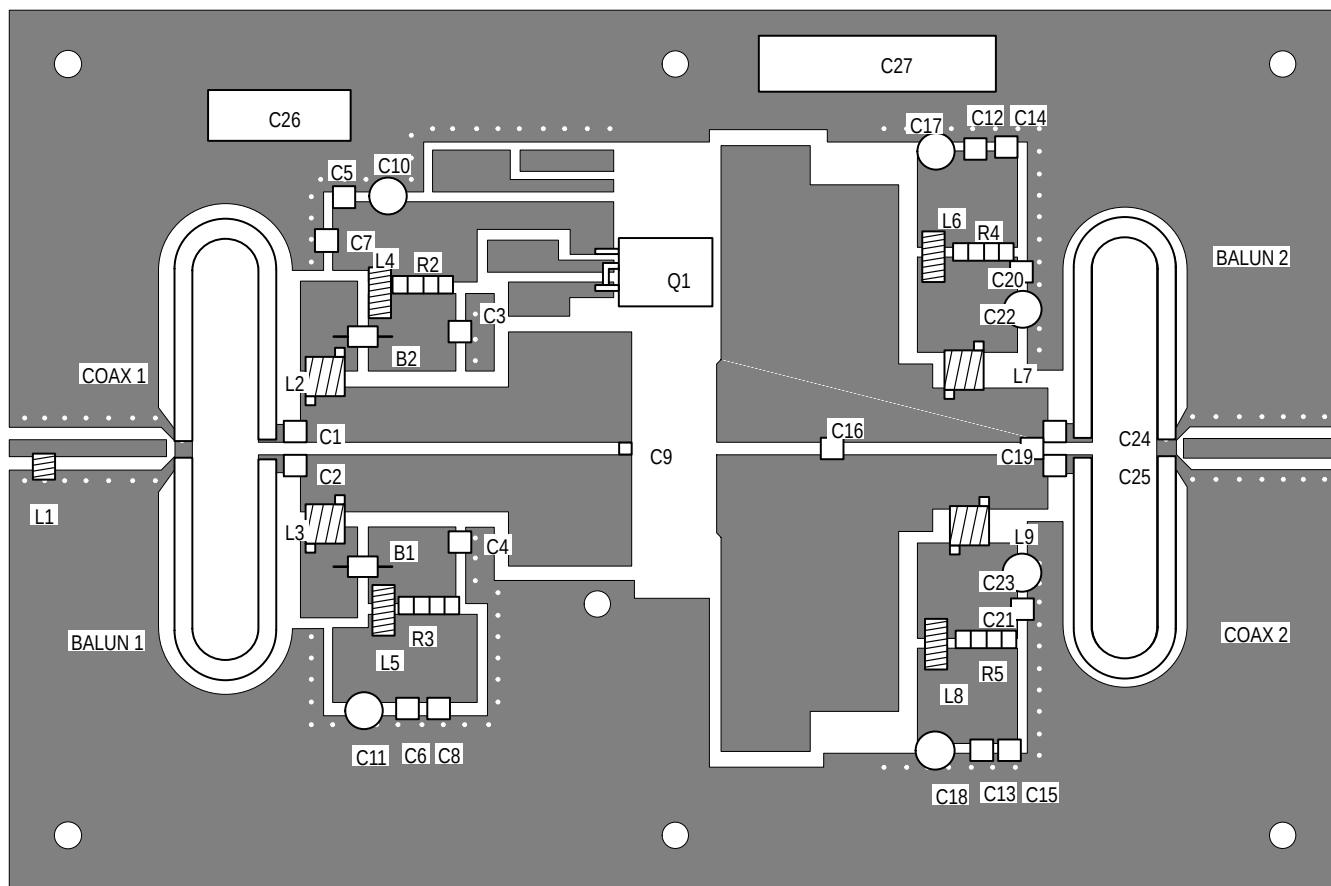
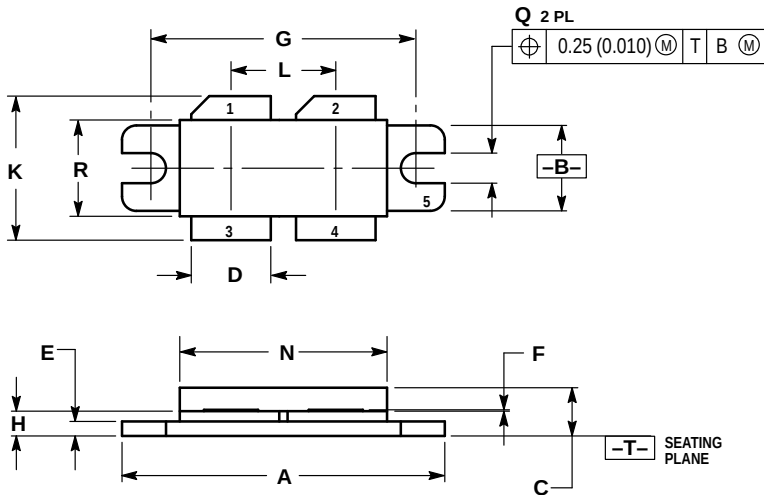


Figure 9. MRF899 Test Fixture Component Layout

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.330	1.350	33.79	34.29
B	0.375	0.395	9.52	10.03
C	0.180	0.205	4.57	5.21
D	0.320	0.340	8.13	8.64
E	0.060	0.070	1.52	1.77
F	0.004	0.006	0.11	0.15
G	1.100 BSC		27.94 BSC	
H	0.082	0.097	2.08	2.46
K	0.580	0.620	14.73	15.75
L	0.435 BSC		11.05 BSC	
N	0.845	0.875	21.46	22.23
Q	0.118	0.130	3.00	3.30
R	0.390	0.410	9.91	10.41

- STYLE 1:
 PIN 1. COLLECTOR
 2. COLLECTOR
 3. BASE
 4. BASE
 5. EMITTER

**CASE 375A-01
 ISSUE O**

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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution;
 P.O. Box 5405, Denver, Colorado 80217. 303-675-2140 or 1-800-441-2447

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4-32-1,
 Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81-3-5487-8488

Mfax™: RMFAX0@email.sps.mot.com – TOUCHTONE 602-244-6609
 – US & Canada ONLY 1-800-774-1848

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,
 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

INTERNET: <http://motorola.com/sps>

